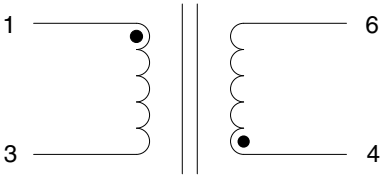
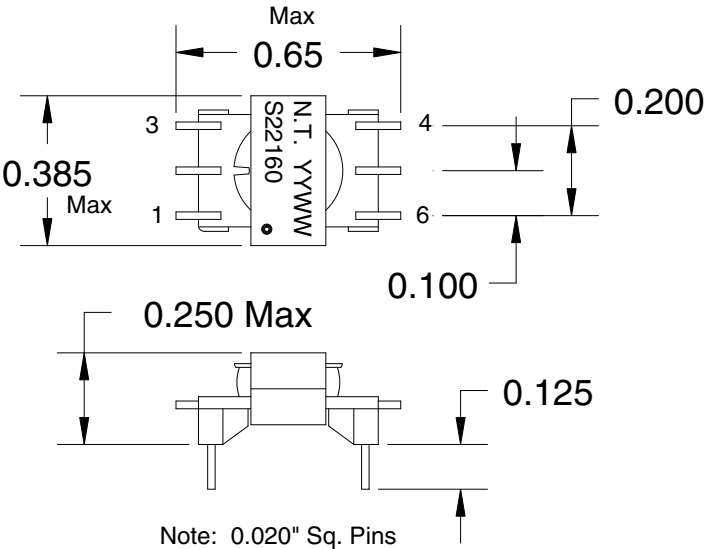


SPECIFICATIONS:

- 1. INDUCTANCE: @ 10 kHz, 0.1 Vrms,  
1 - 3 > 225 uHy
- 2. DCR: mOHMS MAX  
1 - 3 = 0.1  
4 - 6 = 0.1
- 3. LEAKAGE INDUCTANCE: 1 - 3, 0.1V @ 100kHz  
SHORT 4 - 6 < 0.5 uHy
- 4. INTERWINDING CAPACITANCE:  
1 - 3 to 4 - 6 @ 100 KHz, 1.0V < 15 pf
- 5. TURNS AND PHASE:  
1 - 3 : 4 - 6 = 1 : 1 +/- 2%
- 6 DIELECTRIC STRENGTH:  
1500 VAC 1 sec

Note: Designed to operate with Crystal Semiconductor  
CS8401.8402, 8411 & 8412



A								
REV.	DATE	ECN	BY	DESCRIPTION				
TOLERANCES ON				Newava Tech. Watertown, SD 57201 605-886-0264		Transformer Pulse, 1:1		
.XXX + -		.XX + -						ANGLE + -
			DATE					
DRAWN:			SCALE		MODEL		DRAWING NO.	REV.
CHECKED: -			-				S22160	A
APPROVED: -			-		NEXT ASSY:			
THIS PRINT MUST NOT BE COPIED IN WHOLE OR IN PART							OR USED DETRIMENTALLY TO OUR INTEREST	
							SHEET 1 OF 1	